

General description

Femtofarad bidirectional ElectroStatic Discharge (ESD) protection diode in a leadless ultra small DFN1006 Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients. The combination of extremely low capacitance, high ESD maximum rating and ultra small package makes the device ideal for high-speed data line protection and antenna protection applications.

Features and benefits

- Bidirectional ESD protection of one line
- Femtofarad capacitance: $C_j = 0.6\text{pF}$ (Typ)
- Low clamping voltage $V_C = 15\text{ V}@3\text{A}$
- Ultra Low Leakage: nA Level
- Response time is typically $< 1\text{ ns}$
- IEC 61000-4-2; level 4 (ESD)



DFN1006-2L

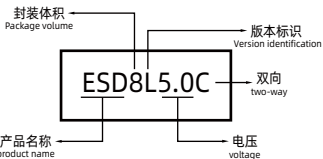
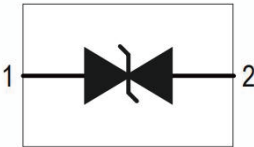
Application information

- 10/100/1000 Mbit/s Ethernet
- FireWire
- High- speed data lines
- Subscriber Identity Module (SIM) card protection
- Cellular handsets and accessories
- Portable electronics
- Communication systems
- Computers and peripherals
- Audio and video equipment
- Antenna protection

Ordering information

Device	Package	Reel Size	Qty(PCS)
ESD8L5.0C	DFN1006-2L	7 Inch	10000

Ordering information

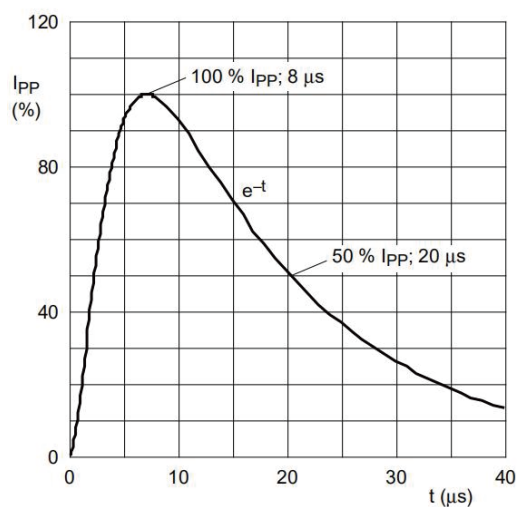
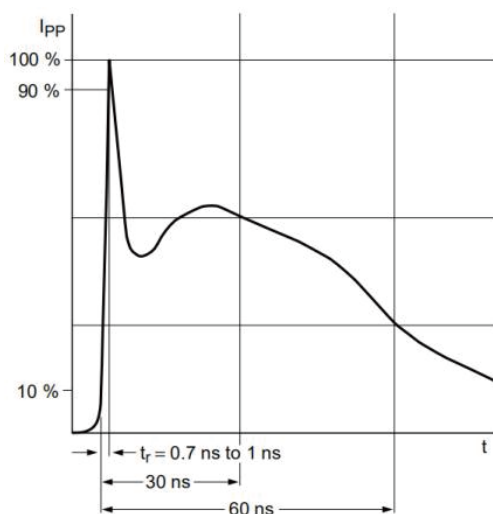
Marking	Naming rule	Graphic symbol
N	 The diagram shows the naming rule for the device ESD8L5.0C. It is a rectangular box with the text 'ESD8L5.0C' inside. Arrows point from labels to parts of the box: '封装体积' (Package volume) points to the top, '版本标识' (Version identification) points to the right, '双向' (two-way) points to the bottom, '电压' (voltage) points to the right, and '产品名称' (product name) points to the left.	 The graphic symbol is a rectangle containing a bidirectional diode symbol. The symbol consists of two triangles pointing towards each other, with a vertical line through the center. The left terminal is labeled '1' and the right terminal is labeled '2'.

Maximum Ratings ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

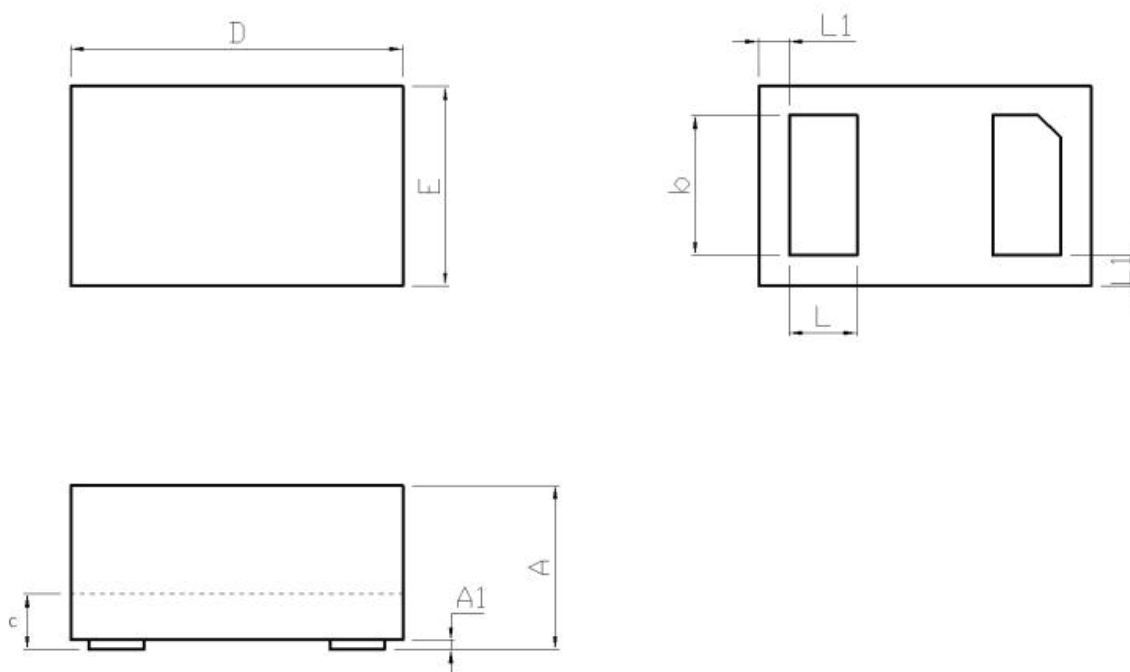
Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p = 8/20\mu\text{s}$)	P_{PPM}	45	W
Peak Pulse Current($t_p = 8/20\mu\text{s}$)	I_{PPM}	3	A
Maximum lead temperature for soldering during 10s	T_L	260	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Operating Temperature Range	T_{OP}	-40 to +125	$^{\circ}\text{C}$
Maximum junction temperature	T_j	150	$^{\circ}\text{C}$
ESD voltage IEC 61000-4-2 (air discharge)	V_{ESD}	15	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V_{ESD}	8	kV

Electrical Characteristics ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V_{RWM}	--	--	5.0	V	
Breakdown Voltage	V_{BR}	6.5	--	9.0	V	$I_T=1\text{mA}$
Leakage Current I_{Leak}	I_R	--	--	100	nA	$V_{RWM}=5\text{V}$
Clamping Voltage	V_C	--	--	15.0	V	$I_{PP}=3\text{A}, T_p=8/20\mu\text{s}$
Junction Capacitance	C_J	--	0.6	0.8	pF	$V_R=0\text{V}, f=1\text{MHz}$



DFN1006-2L Package Outline Dimensions



DFN1006-2L (mm)			
DIM	MIN	TYP.	MAX
A	0.40	0.50	0.55
A1	0	0.02	0.05
b	0.45	0.5	0.55
c	0.1	0.15	0.18
D	0.95	1.00	1.05
E	0.55	0.60	0.65
L	0.20	0.25	0.30
L1	0.035	0.05	0.065